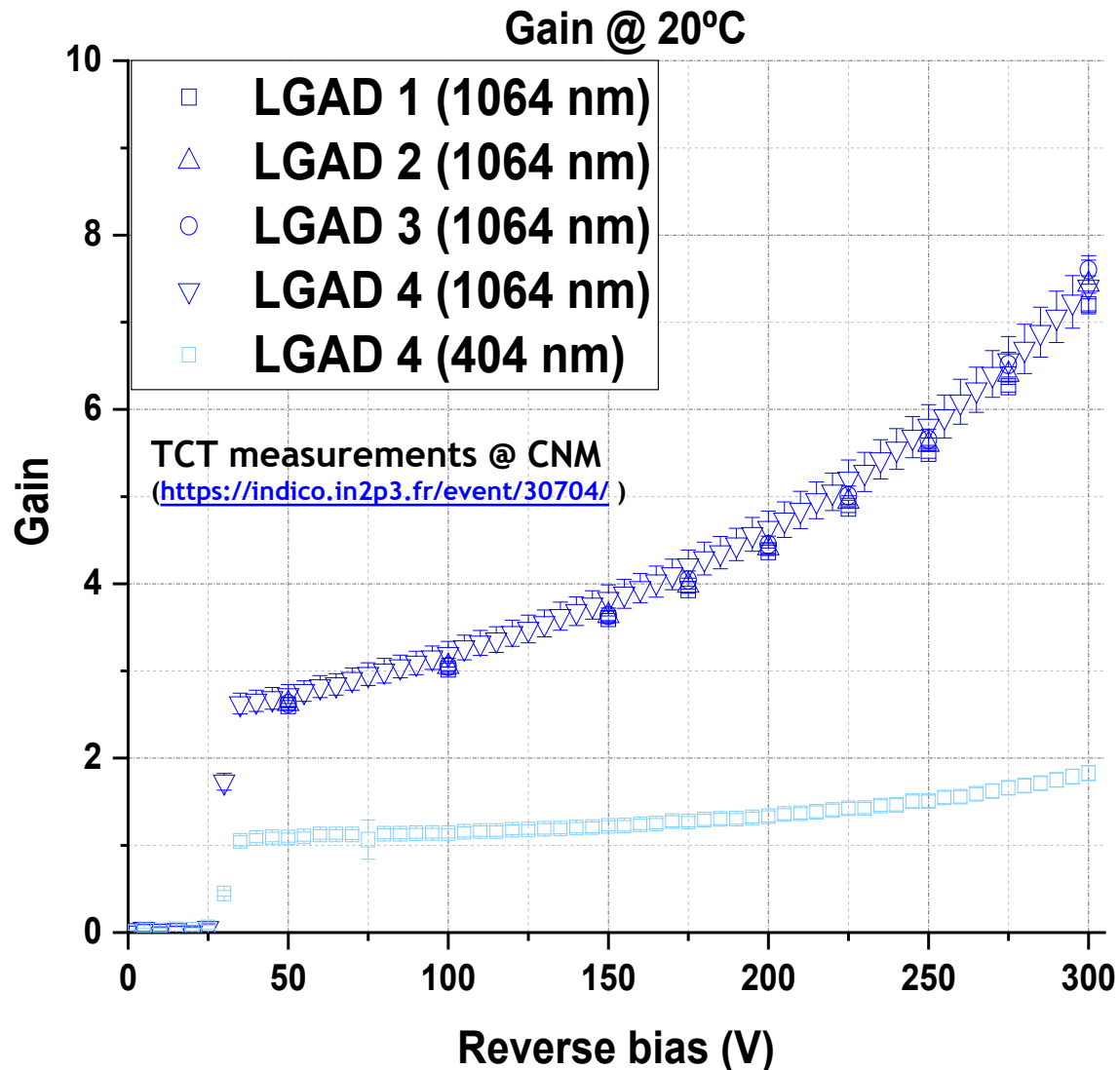


Gain measurements and spectral response of the latest IMB-CNM fabricated nLGAD

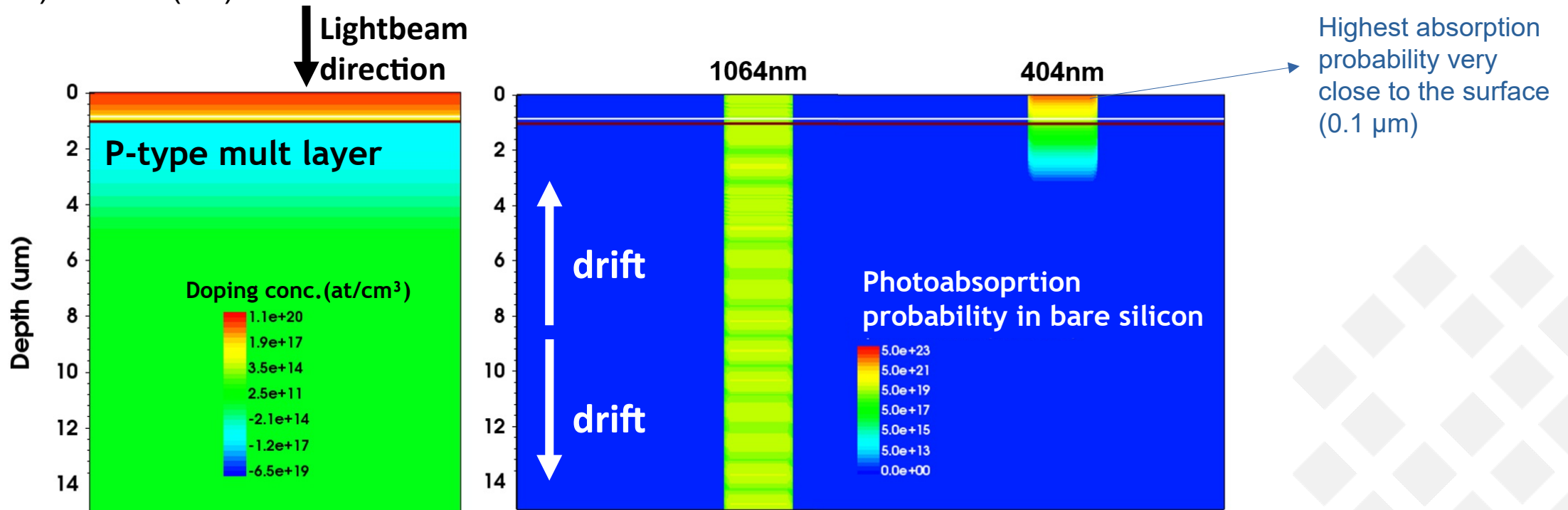
P. Fernandez-Martinez, J. Villegas, M. Manojlovic,
N. Moffat, S. Hidalgo, G. Pellegrini

- Motivation
 - LGAD gain response to high- and low-penetrating particles
 - nLGAD concept
- First CNM nLGAD engineering run: CNM-nLG1-v1
- Second CNM nLGAD engineering run: CNM-nLG1-v2
 - TCT Gain response to UV, visible and IR light
- Road ahead

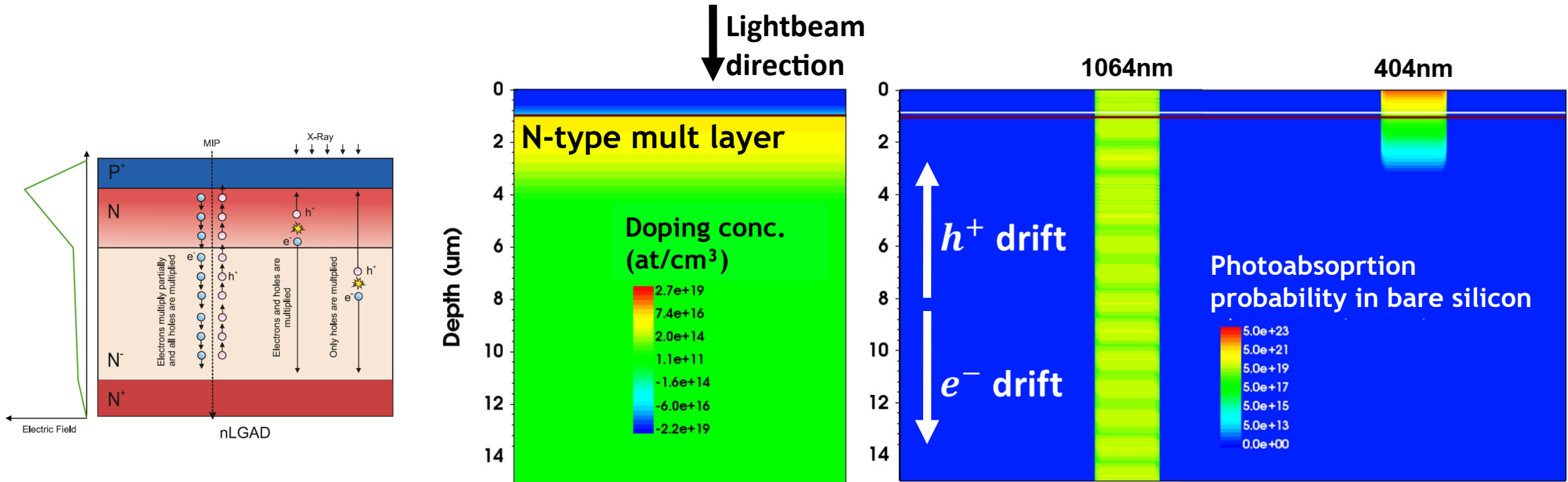


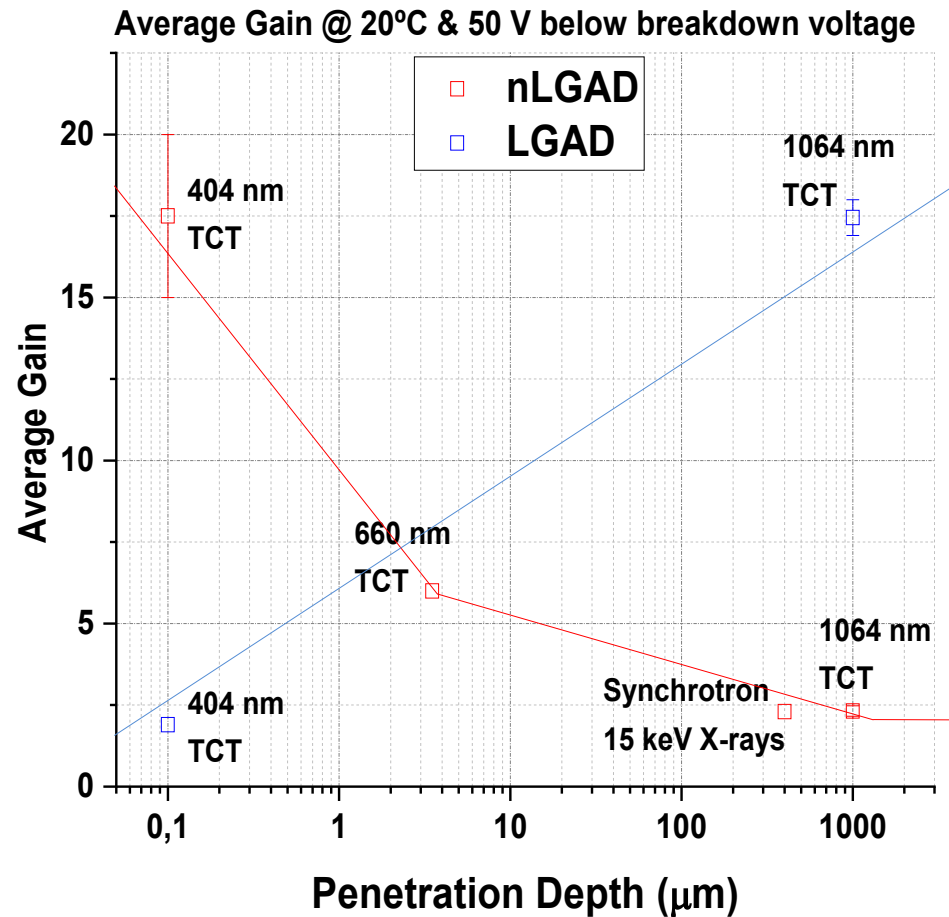
- Typical LGADs (thickness = 50 μ) have a **lower gain response for low-penetrating** (LP) particles than for high-penetrating (HP) ones
- Although the charge generation mechanism differs, the effect is equally expected for photons and charged particles
- Photon detection: penetration depth (goes inversely with attenuation) in silicon:
 - 404 nm (blue) $\rightarrow \approx 0.1 \mu\text{m} < 50 \mu\text{m}$
 - 1064 nm (IR) $\rightarrow \approx 1000 \mu\text{m} > 50 \mu\text{m}$
- Can we build up an **LGAD more sensitive to low penetrating particles**, such as soft-X rays or low energy protons?

- Traditional LGADs: different gain response for HP (e.g. 1064 nm photons) and LP (e.g. 404 nm photons) species: Who triggers the avalanche?
 - HP particles: **Avalanche mainly triggered by e⁻** crossing the multiplication layer on their drift way.
 - LP particles: e-h pairs almost exclusively generated within the n-side of the junction. **Avalanche mainly triggered by h⁺**
- Impact ionization rate is higher for electrons than for holes [[https://doi.org/10.1016/0038-1101\(70\)90139-5](https://doi.org/10.1016/0038-1101(70)90139-5)]. Therefore: Gain (HP) > Gain (LP)



- **nLGAD concept:** Inverting implantation polarity of all the layers, we get an electron-driven avalanche for LP species:
 - Gain LP > Gain HP

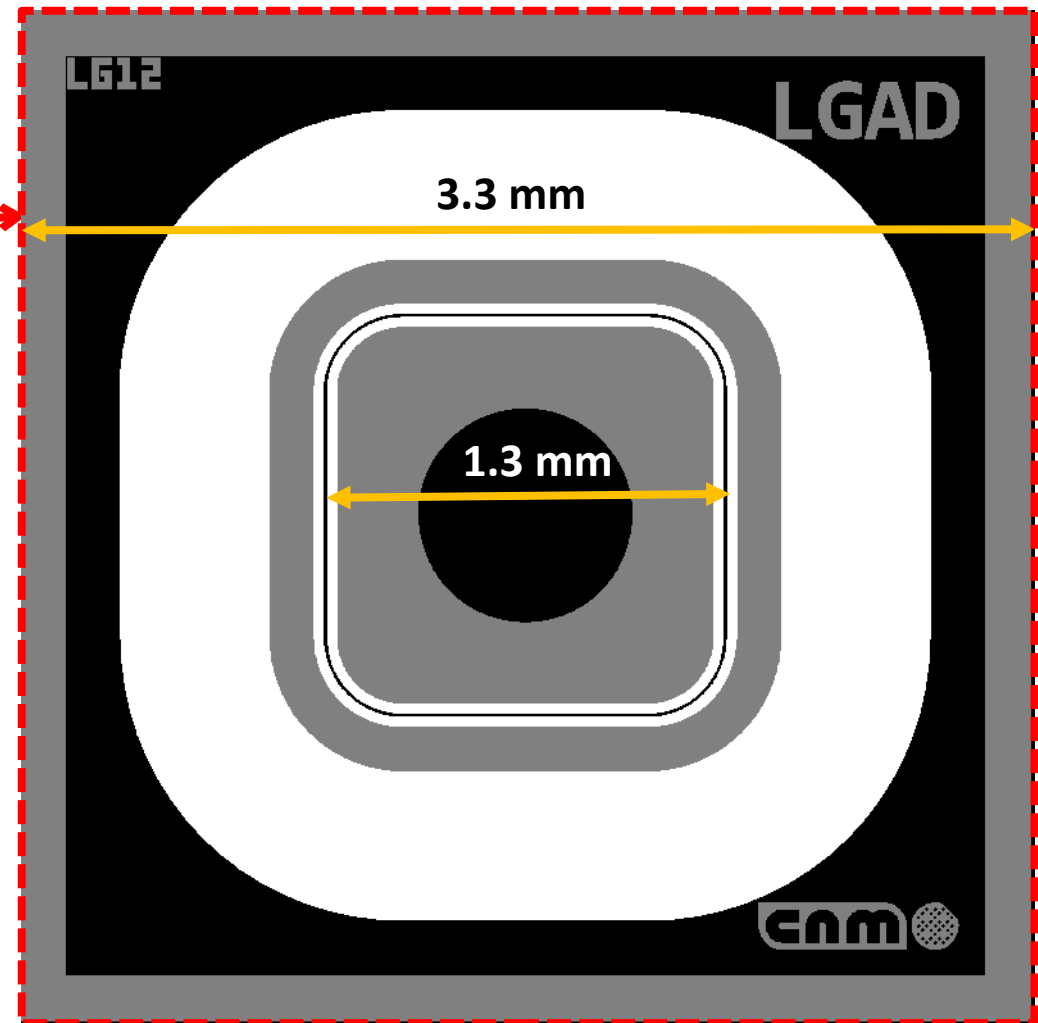
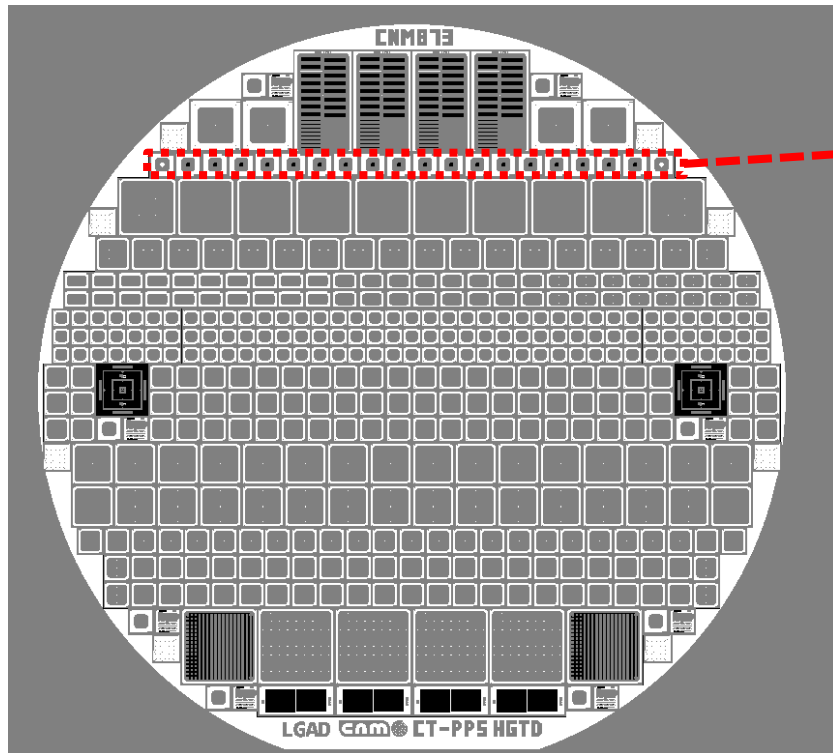




CNM-nLG1-v1

- Mask containing only single-pad diodes. 275 µm thick devices
- Gain measurements of the first prototypes showed the potential of nLGADs for LP particles detection
 - Plot and analysis reported in:
 - <https://doi.org/10.1016/j.nima.2023.168377>
 - Penetration depth data:
 - <https://www.nist.gov/pml/x-ray-mass-attenuation-coefficients> (NIST)
 - <https://doi.org/10.1002/pip.4670030303>

CNM-nLG1-v2



275 μ m thick

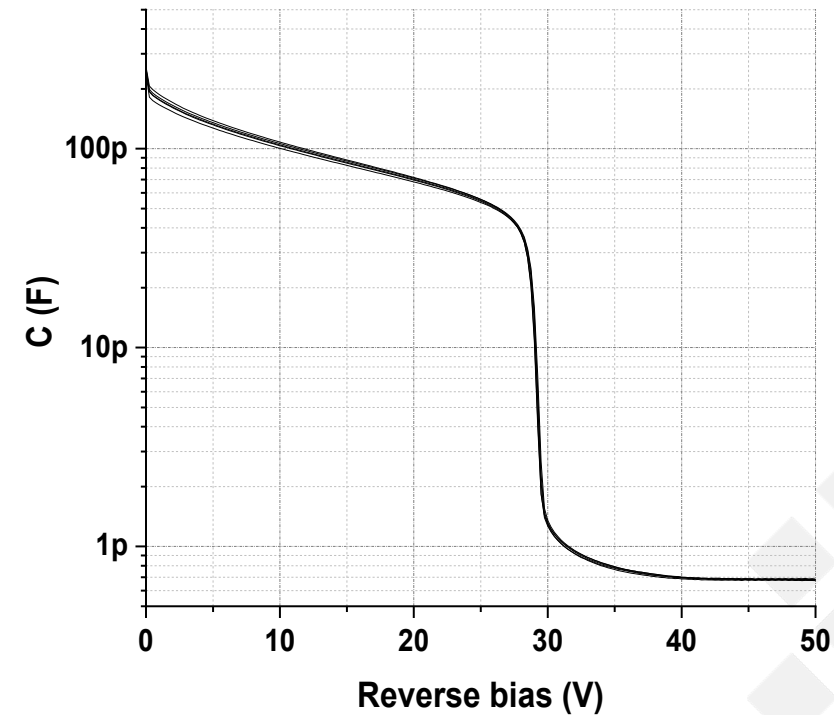
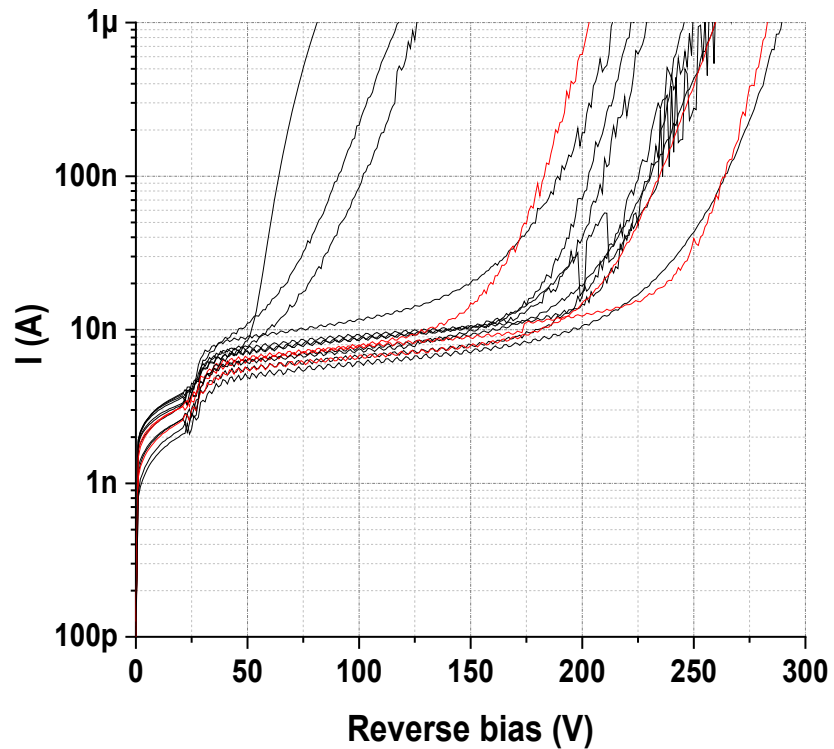
Adapted mask set with several structures, mainly:

- Single pad devices of 1.3 and 2.6 mm
- Pixelated devices (design issue)

Selected samples (single-pad diodes) TCT-tested: UV light (369 nm), visible light (404 nm) and IR light (1064 nm)



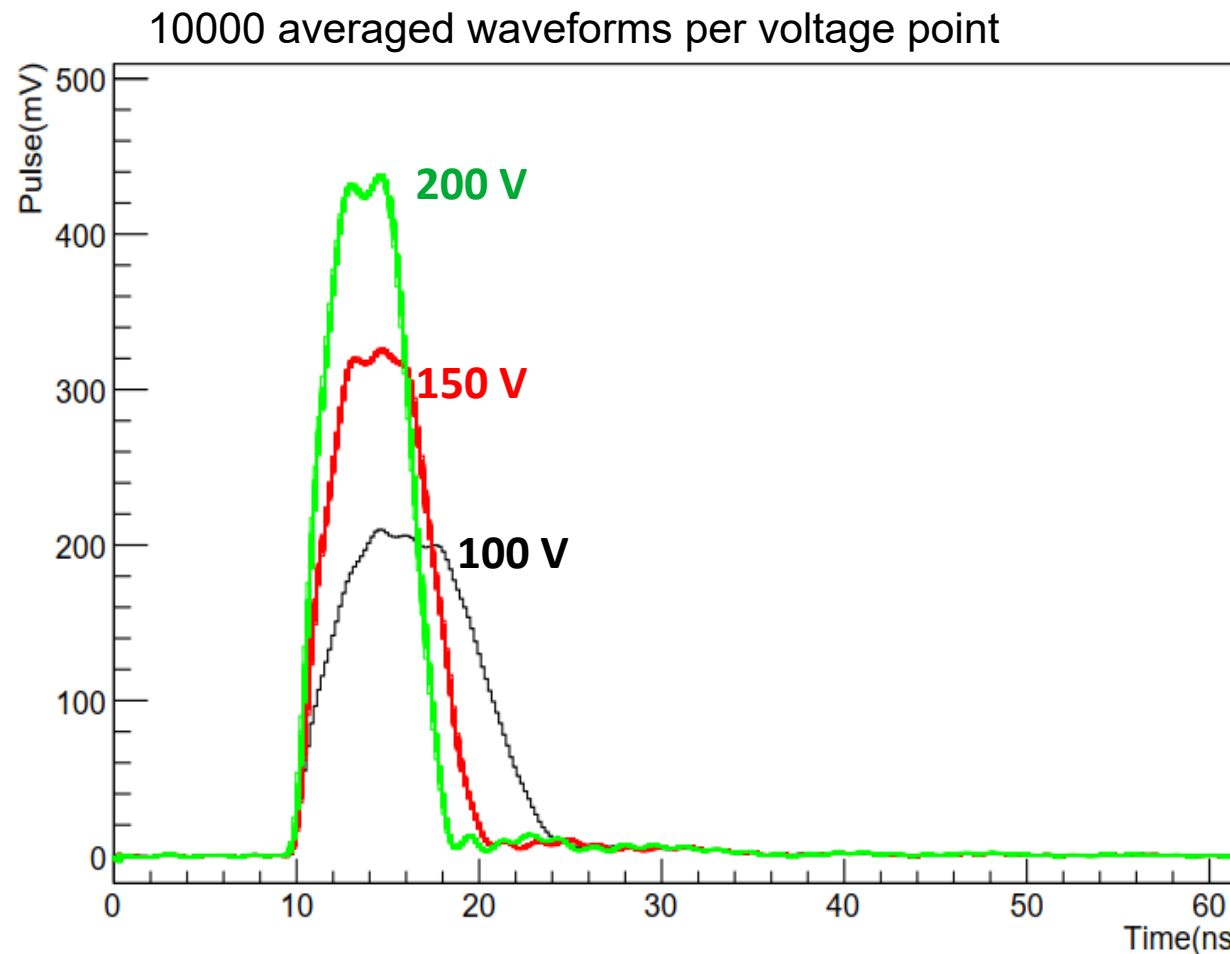
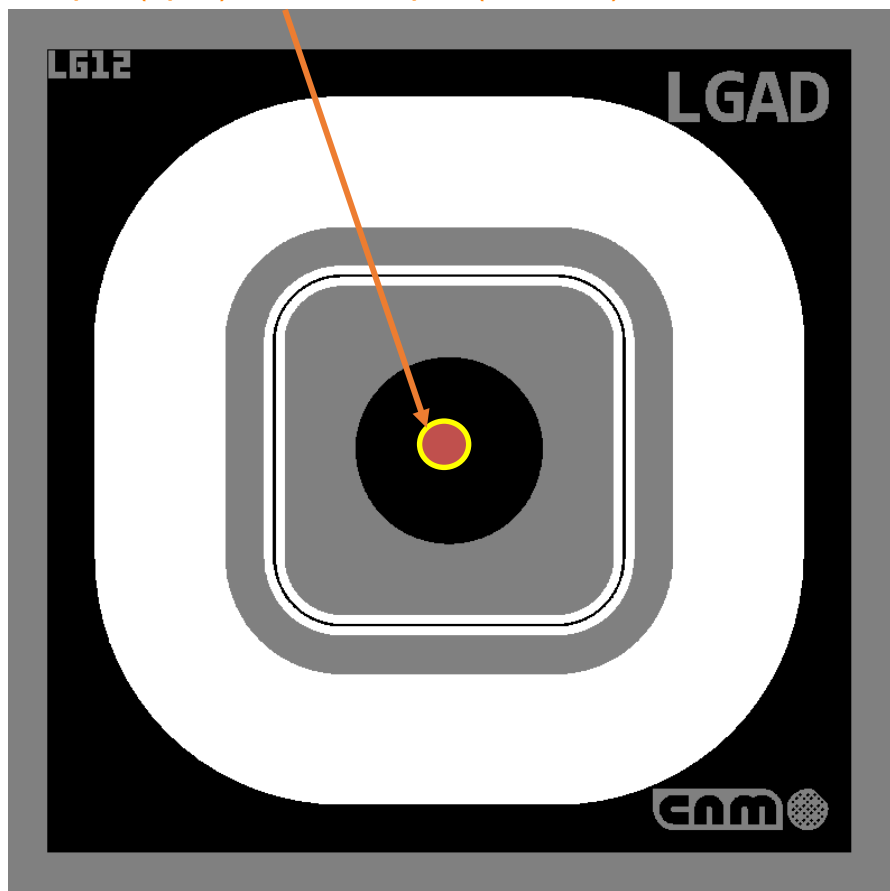
[[J. Villegas - TREDI2024](#)]



TCT 404 nm light, Max intensity, 1kHz, 20°C → Voltage Scans in the center @ 20°C

[J. Villegas - TREDI2024]

Projection of beam on entrance window :
 $d \approx 60 \mu\text{m}$ (spot) < $d = 700 \mu\text{m}$ (window)

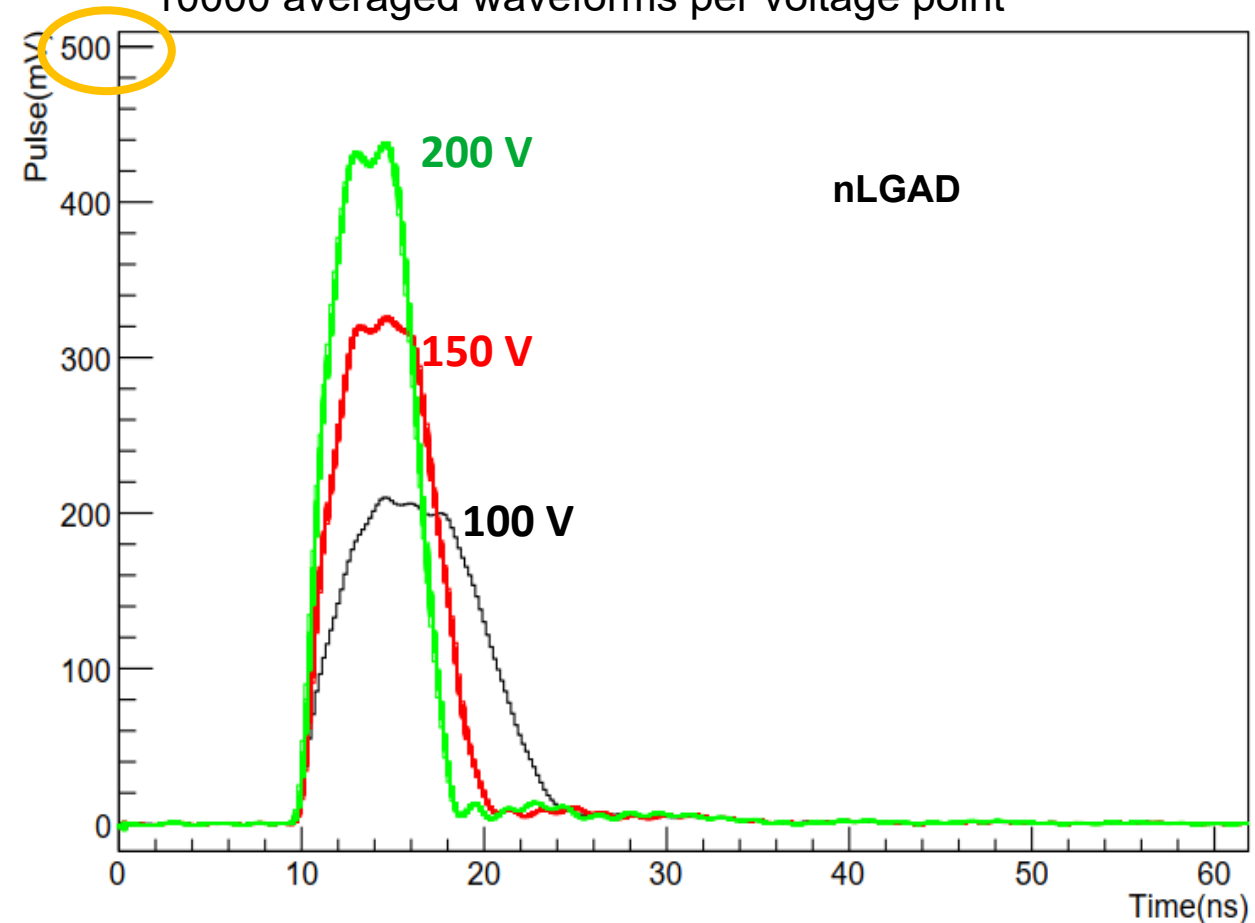
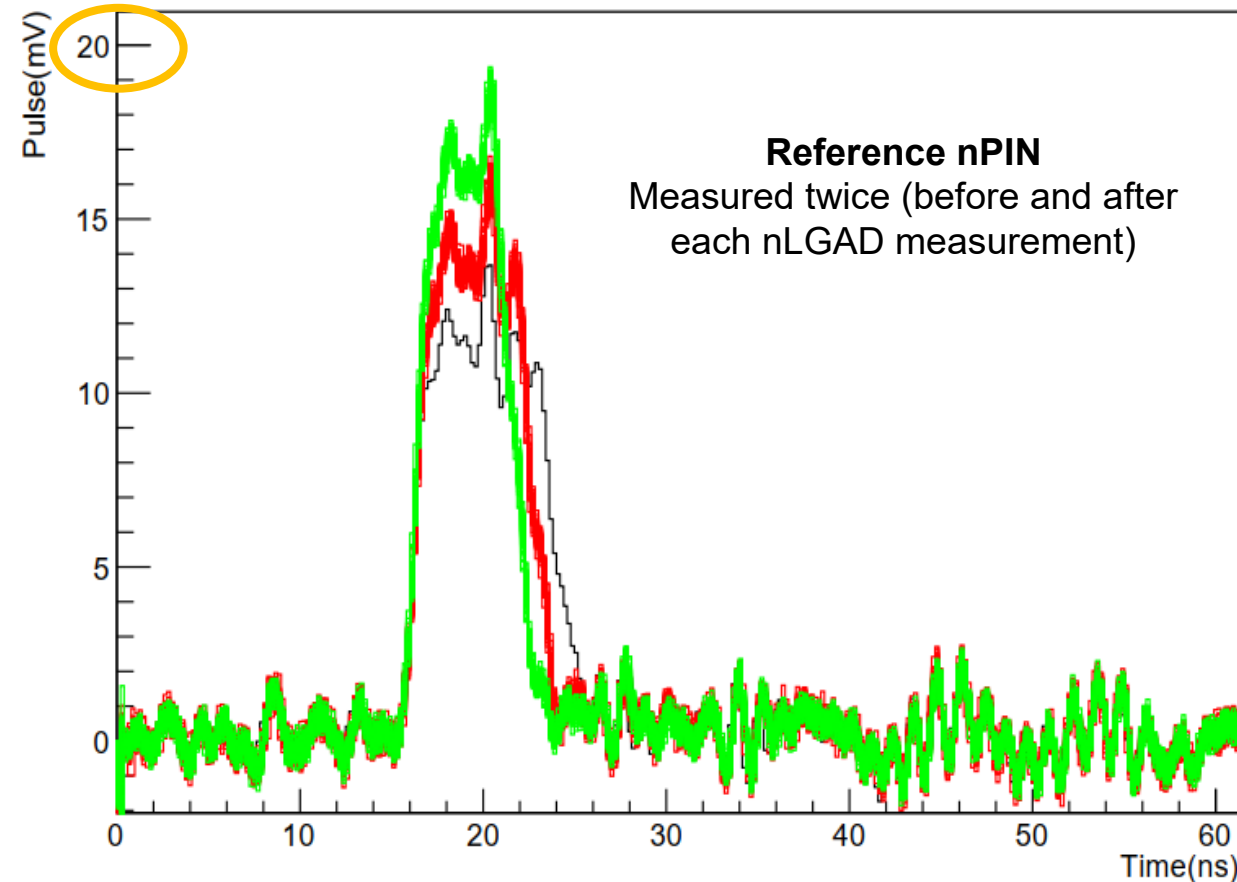


TCT 404 nm light, Max intensity, 1kHz, 20°C → Voltage Scans in the center @ 20°C

[J. Villegas - TREDI2024]

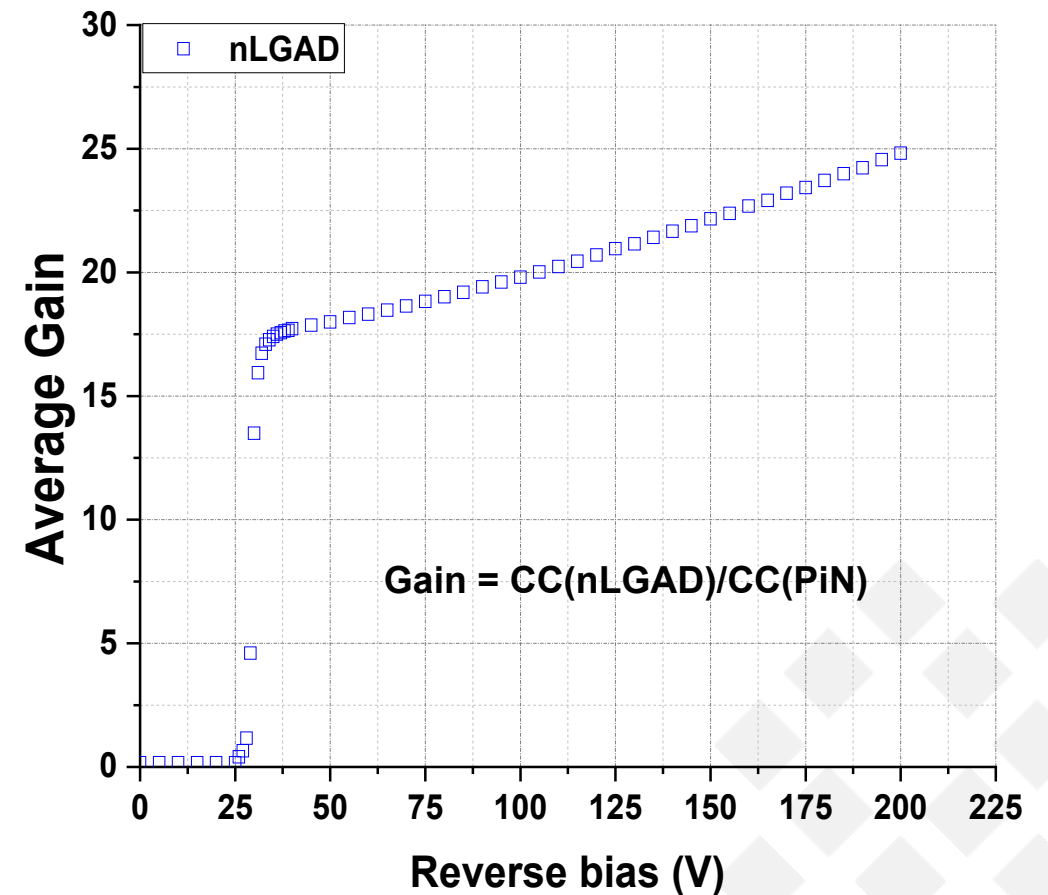
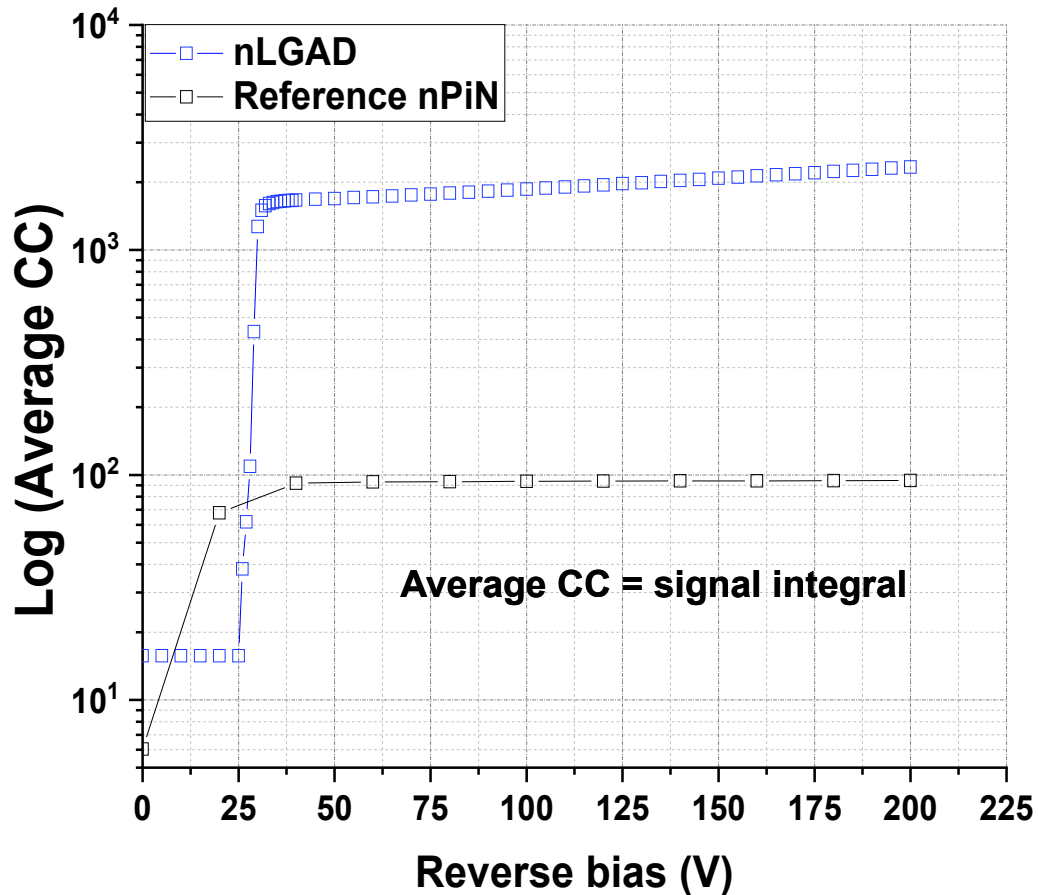
10000 averaged waveforms per voltage point

10000 averaged waveforms per voltage point



TCT 404 nm light, Max intensity, 1kHz, 20°C → Voltage Scans in the center @ 20°C

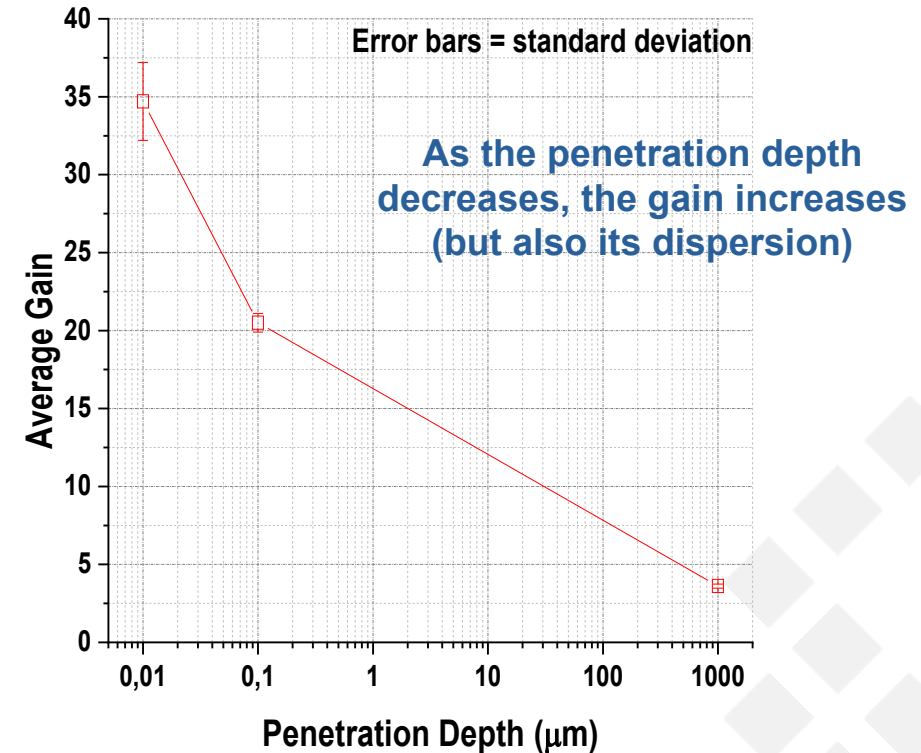
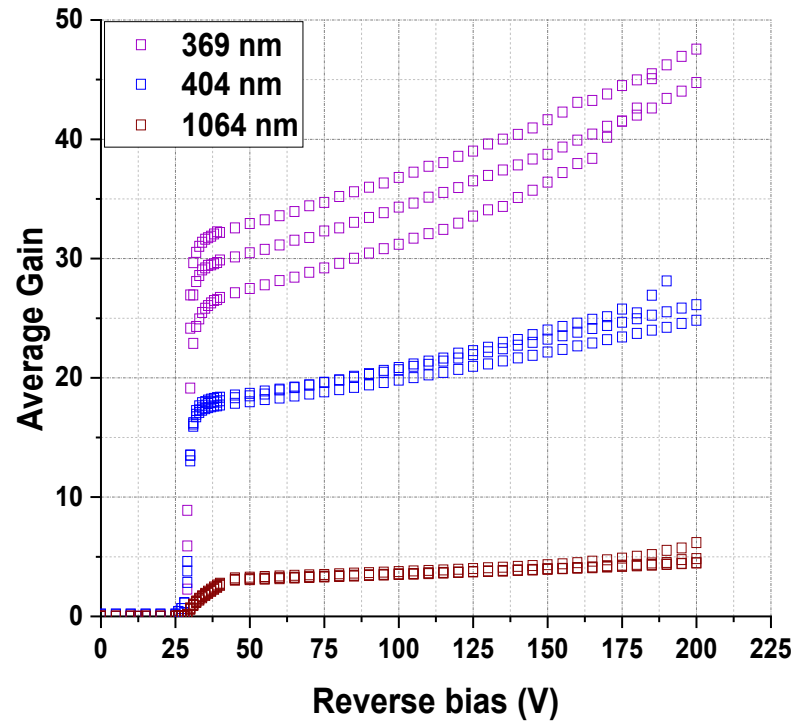
[J. Villegas - TREDI2024]



Selected samples (single-pad diodes) TCT-tested: UV light (369 nm), visible light (404 nm) and IR light (1064 nm)



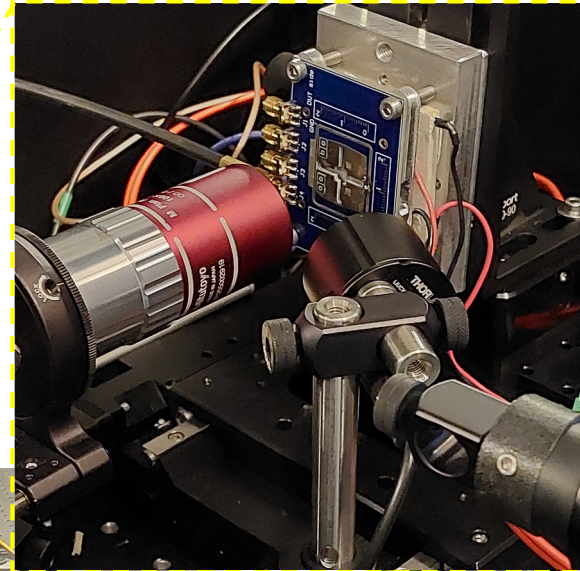
[J. Villegas - TREDI2024]



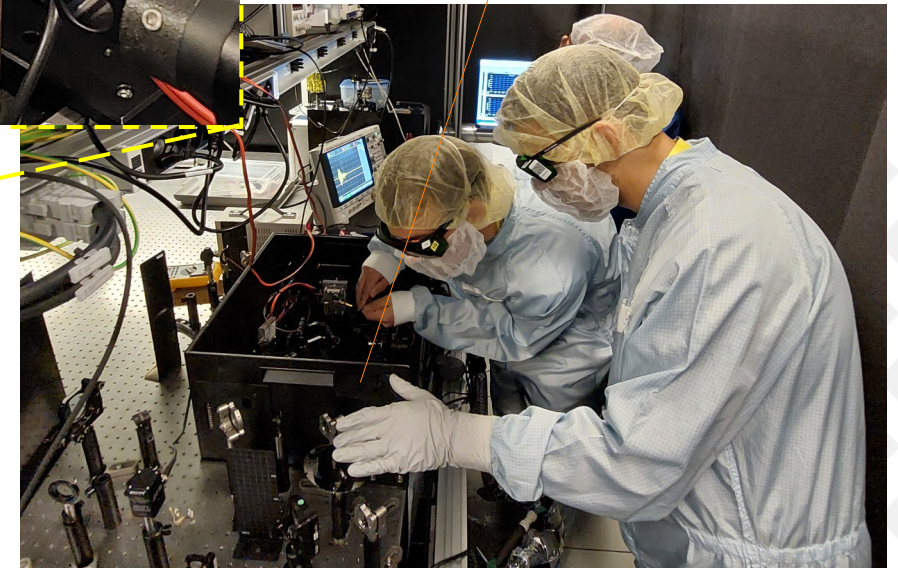
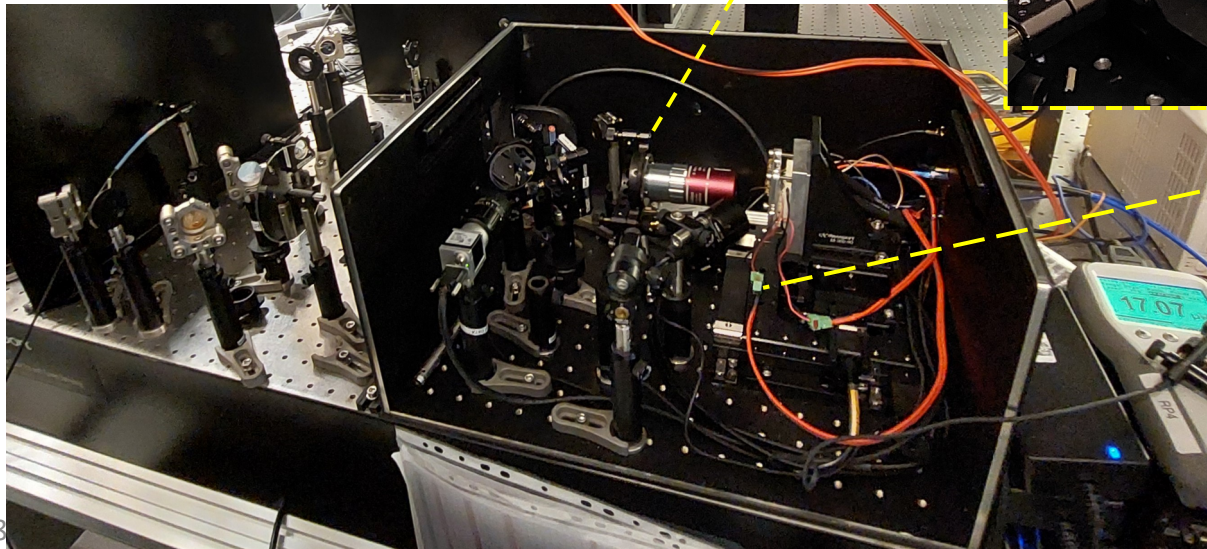


Laser beam time in ELI-ERIC (Czech Rep.): Early June 2024

- Same samples. UV-range explored more deeply (250 nm to 390 nm).

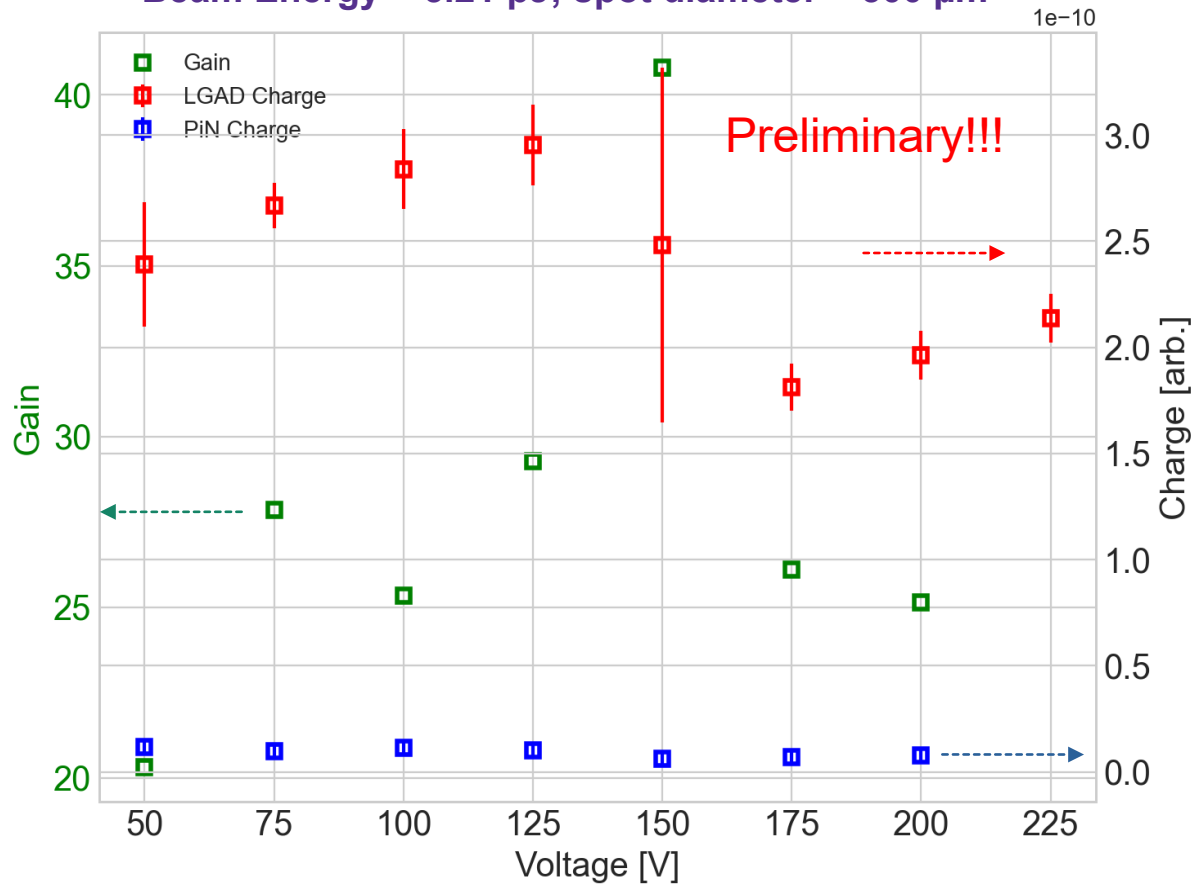


Control on the beam intensity



Preliminary results with 250 nm

Beam Energy = 5.21 pJ; spot diameter \approx 300 μ m



- Tested with different wavelengths (250-390 nm)
- Wide range of intensities and voltage bias
- Very focusable laser (1 μ m spot by default)
- [Results still under analysis](#)
- Clear gain for LGADs even at 250 nm
- PiN data harder to analyse
- Seem to have gain suppression, in particular with higher intensities
 - Most of the data were taken with controlled defocus (to enlarge the spot)
- Second test campaign in Jul/Aug

- Further studies on **Run 2** (CNM-nLG1-v2):
 - Tests all single-pad devices (study of gain uniformity)
 - Second test campaign in ELI (end July 2024): systematic measurements at different WL and intensities
 - TPA measurements ongoing at CERN
 - Gain measurements with X-ray photons and low-energy protons (CNA-Sevilla)
- New **Run 3** (CNM-nLG2-v1) just finished:
 - Single pads only, mostly 3.3x3.3 mm². nLGAD and PiN
 - Passivation removed from the entrance window and low-energy implant for the ohmic contact
 - 150 mm wafers
- **Plans for the future:**
 - Promising scenario with soft X-ray applications which utilize water window ($E \sim 500$ eV)
 - We want to couple to Timepix3/Timepix4 ASICs and performe sub-threshold detection unsing the internal gain of the LGAD
 - Many potential applications on the UV range



Thanks for your attention

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Thanks for your attention!